

Notice of References Cited

Application/Control No.
10/045,278

Applicant(s)/Patent Under
Reexamination
GEHRING ET AL.

Examiner
Marcos D. Pizarro-Crespo

Art Unit
2814

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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	B	US-6,261,964	07-2001	Wu et al.	438/705
	C	US-6,316,293	11-2001	Fang, Hao	438/142
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	L	US-			
	M	US-			

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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Ghandhi, VLSI Fabrication Principles: Silicon and Gallium Arsenide, 1994, John Wiley and Sons, Inc., New York, 2nd edition, pp.589, 620
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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